

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013

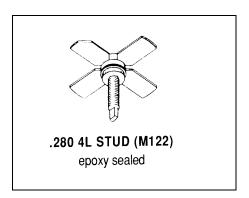
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#### MS1426

# RF & MICROWAVE TRANSISTORS UHF MOBILE APPLICATIONS

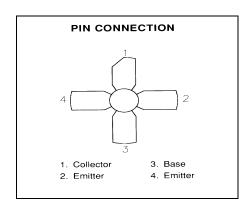
#### **Features**

- 470 MHz
- 12.5 VOLTS
- P<sub>OUT</sub> = 10 WATTS
- $G_P = 8.0 \text{ dB MINIMUM}$
- COMMON EMITTER CONFIRGURATION



#### **DESCRIPTION:**

The MS1426 is a epitaxial silicon NPN planar transistor designed for Class C driver applications in the 450 - 512 MHz frequency range. This device uses an emitter ballasted die geometry specifically designed for optimum stable power gain, maximum efficiency and infinite VSWR capability.



## ABSOLUTE MAXIMUM RATINGS (Tcase = $25^{\circ}$ C)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	36	V
V <sub>CEO</sub>	Collector-Emitter Voltage	16	V
V <sub>CES</sub>	Collector-Emitter Voltage	36	V
V <sub>EBO</sub>	Emitter-Base Voltage	4.0	V
Ic	Device Current	2.5	Α
P <sub>DISS</sub>	Power Dissipation	58	W
<b>T</b> J	Junction Temperature	200	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C

### **Thermal Data**

R <sub>TH(J-C)</sub> Junction-	case Thermal Resistance	3.0	°C/W
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# **ELECTRICAL SPECIFICATIONS (Tcase = 25°C) STATIC**

Symbol	Test Conditions		Value		Unit	
Symbol	rest Conditions		Min.	Typ.	Max.	Offic
BV <sub>CES</sub>	I <sub>C</sub> = 25 mA	$V_{BE} = 0 V$	36			V
BV <sub>CEO</sub>	I <sub>C</sub> = 20 mA	I <sub>B</sub> = 0 mA	16			V
BV <sub>EBO</sub>	I <sub>E</sub> = 10 mA	$I_C = 0 \text{ mA}$	4.0			V
I <sub>CES</sub>	V <sub>CE</sub> = 10 V	I <sub>E</sub> = 0 mA			3.0	mA
I <sub>CBO</sub>	V <sub>CB</sub> = 15V	I <sub>E</sub> = 0 mA			2.0	mA
H <sub>FE</sub>	V <sub>CE</sub> = 5 V	I <sub>C</sub> = 1 A	10		150	

#### **DYNAMIC**

Symbol	Test Conditions		Value			Unit	
Syllibol			Min.	Typ.	Max.	Onit	
P <sub>out</sub>	f = 470 MHz	$P_{IN} = 2.0W$	$V_{CE} = 12.5V$	10			W
G <sub>P</sub>	f = 470 MHz	P <sub>IN</sub> = 2.0W	V <sub>CE</sub> = 12.5V	7			dB
Сов	f = 1 MHz	$V_{CB} = 12.5V$				26	pf

#### **IMPEDANCE DATA**

FREQ	$Z_IN(\Omega)$	$Z_{CL}(\Omega)$
470MHz	1.5 - j2.7	5.7 + j1.5

 $P_{IN} = 2.0W$  $V_{CE} = 12.5V$ 





#### PACKAGE MECHANICAL DATA

